

# Study of silicon sensors for precise timing measurement

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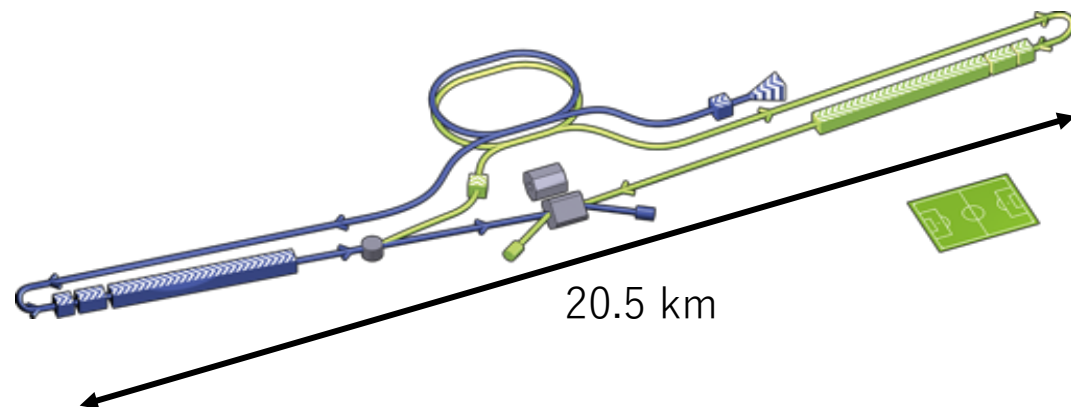
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Stéphane Callier (Omega/IN2P3)

# International Linear Collider (ILC)

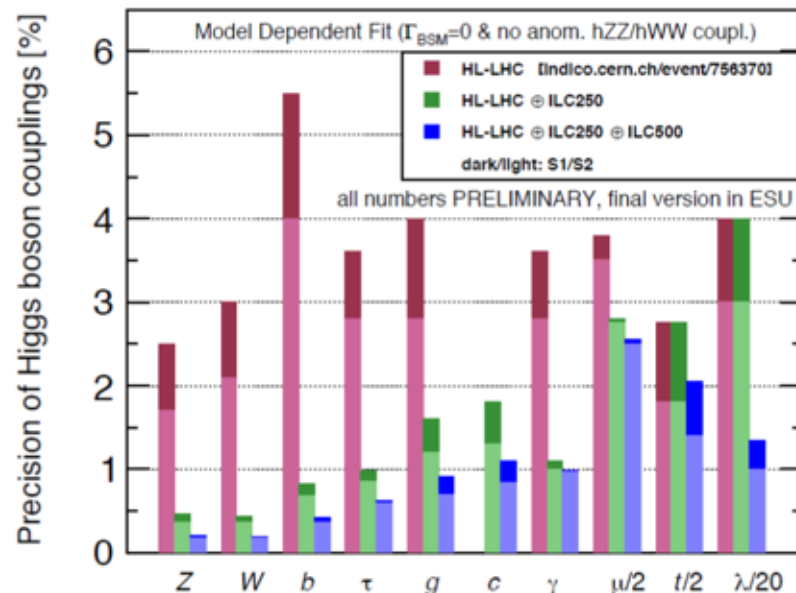
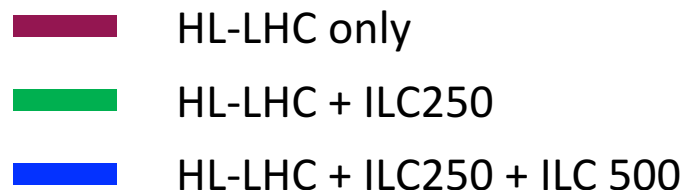
## ➤ What is the ILC ?

- Electron and positron collider
- $\sqrt{s} = 250$  GeV  
→ Up to 1 TeV in the future
- Length : about 20 km
- Search for new physics with precise measurement of Higgs and other particles



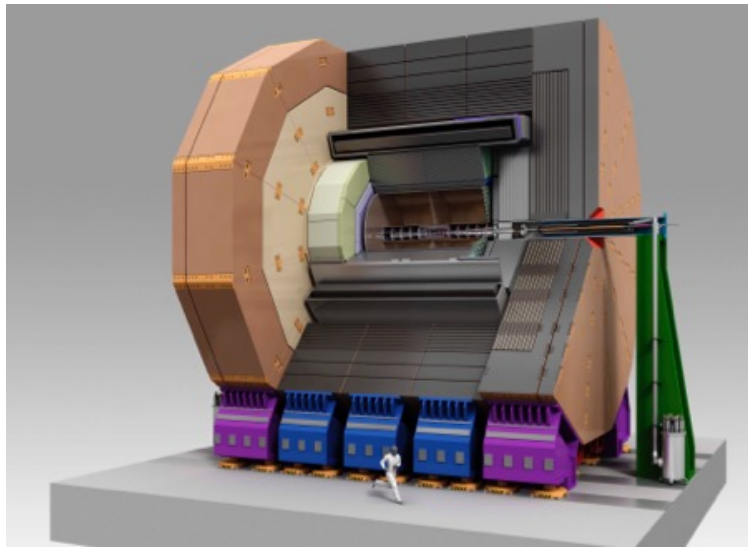
## ➤ Expectation of Higgs physic in ILC

The precise of Higgs couplings will be improved

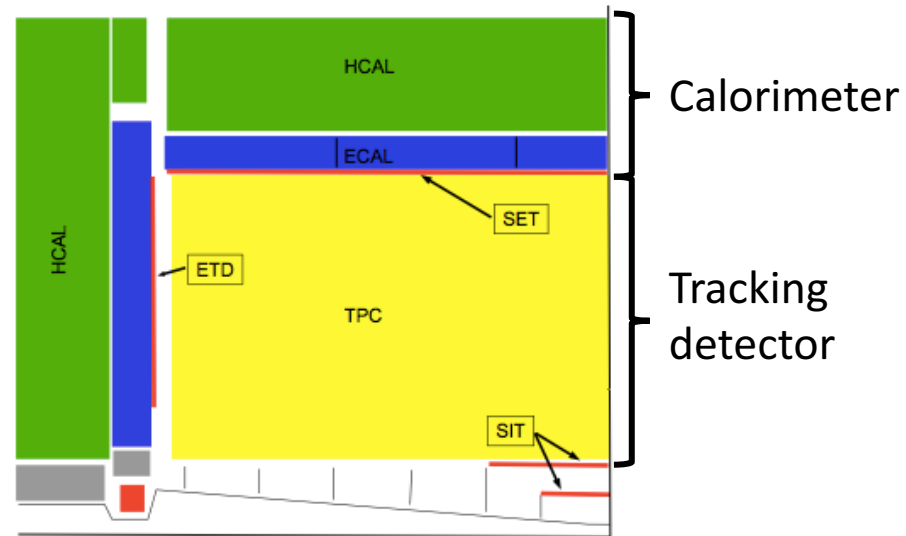


# International Large Detector (ILD)

- One of the detectors placed at the collision point
- Mainly charged particles are detected by tracking detector, and neutral particles are detected by calorimeter
- In the TPC,  $dE/dx$  is calculated by the collected charge to identify the particles



International Large Detector (ILD)



# Identification of particles

- Time of flight

Particles have differences of flight time depending on their mass

Particle	mass	$\beta = \frac{v}{c}$ (5 GeV)
K	494 MeV/c <sup>2</sup>	0.9951
$\pi$	139 MeV/c <sup>2</sup>	0.9996

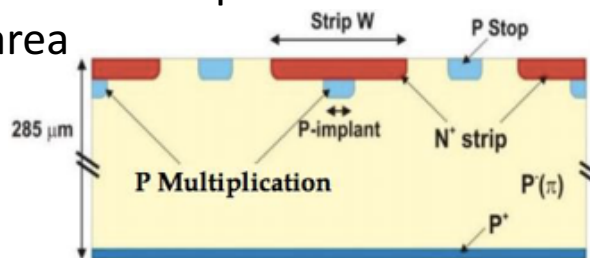
In order to identify K and  $\pi$ , we need to have time resolution less than 50 psec

➤ LGAD (Low Gain Avalanche Diode)

→ The time resolution : ~30 psec (in ATLAS study)

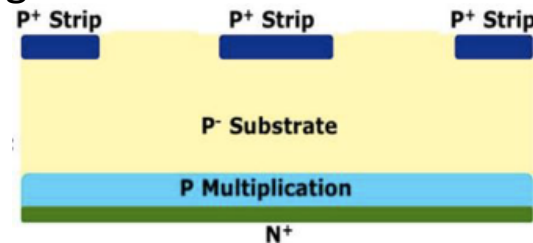
- Reach-through type

- Fast charge collection speed
- Insensitive area

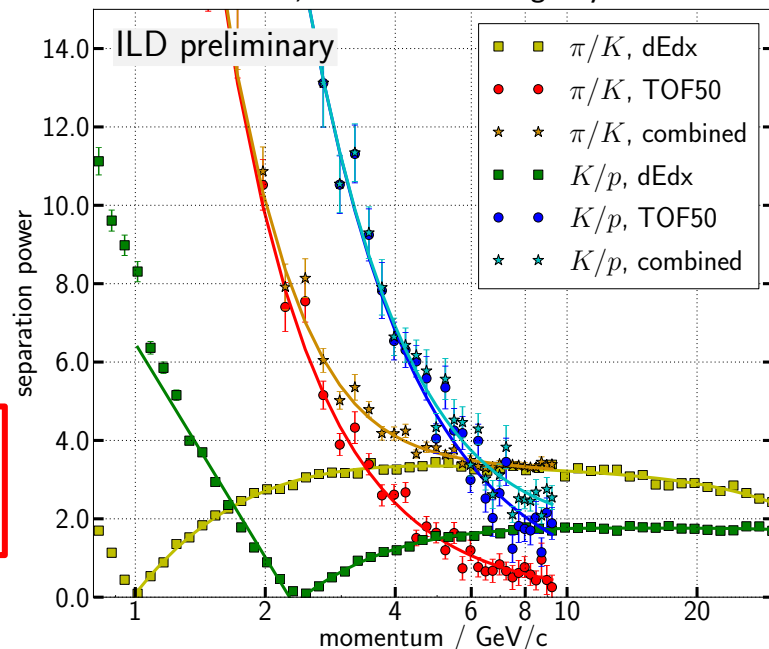


- Inverse type

- Multiplication layer covered bottom layer
- Less variation in gain



“Particle ID Performance with dE/dx and TOF”  
Uli Einhaus, ILD Benchmarking Days 2018





# Avalanche Photo Diode

LGADs have same structure as APDs → We study APDs for LGAD development

Model number	Type	$V_{br}$	Size
S12023-10A	Reach-through	139 V	$\phi$ 1 mm
S8664-10K	Inverse	417 V	$\phi$ 1 mm
pkg-10	Reach-through	about 250 V	$\phi$ 1 mm
pkg-20	Reach-through	about 120 V	$\phi$ 1 mm
S2384	Reach-through	159 V	$\phi$ 2 mm
S3884	Reach-through	189 V	$\phi$ 1.5 mm
S8664-20K	Inverse	425 V	$\phi$ 2 mm
S8664-55	Inverse	433 V	$5 \times 5 \text{ mm}^2$



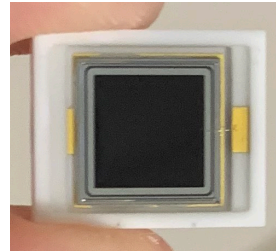
S12023-10A



S8664-10K



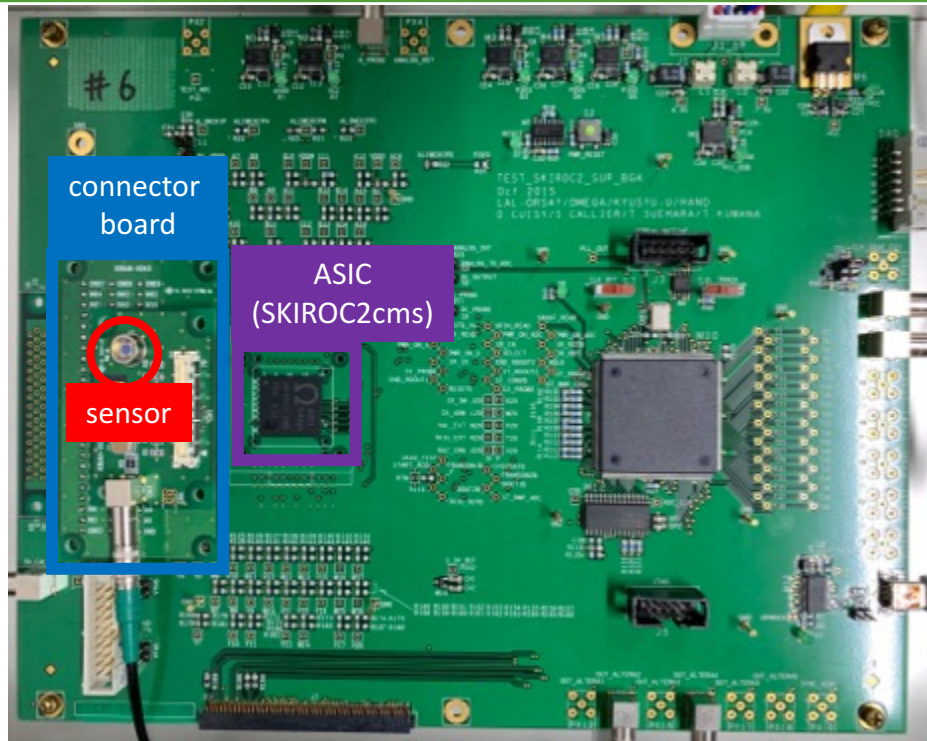
pkg-10, pkg-20



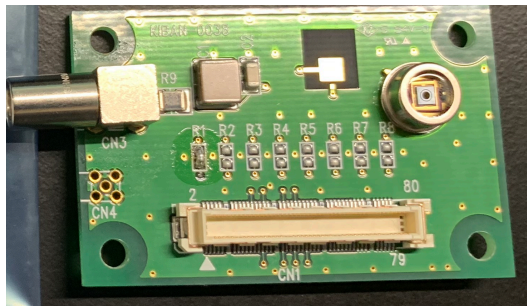
S8664-55

LGAD prototype (for LHC?)

# Set up of DAQ



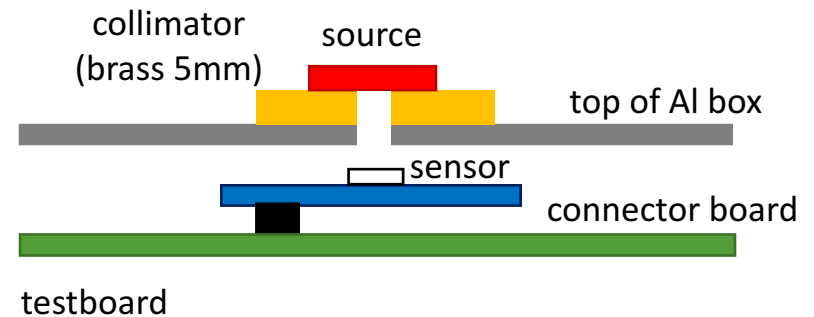
Testboard#6 (SKIROC2cms is soldered)



connector board (with S8664-10K)



into the Al box



## Sources

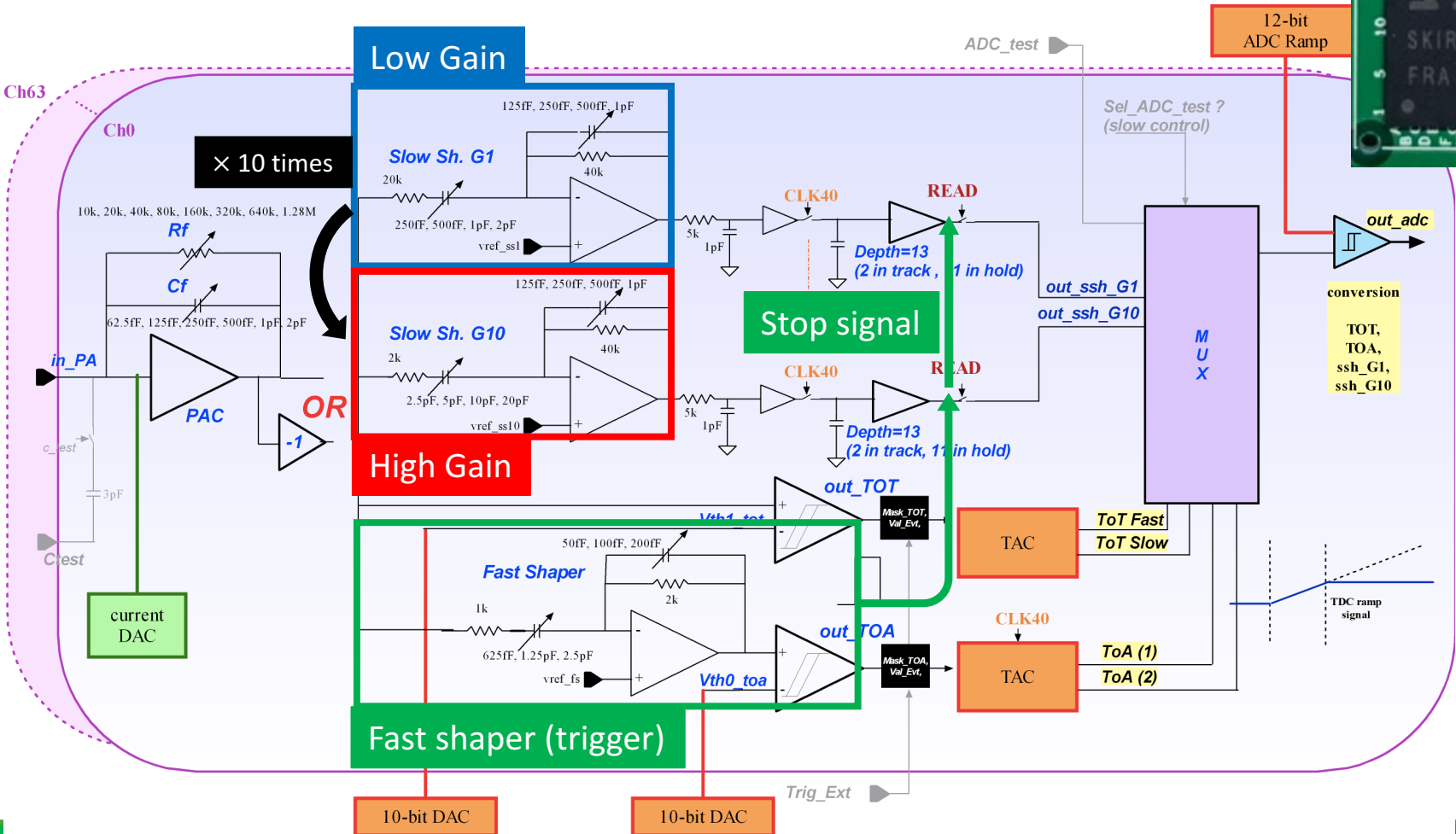
$\gamma$  source :  $^{133}\text{Ba}$ , 81 keV + 356 keV  
(compton edge : 207 keV)

$\beta$  source :  $^{90}\text{Sr}$ , 2.2 MeV (Max)

# SKIROC2cms

- SKIROC2cms is an ASIC to readout signals from sensors

- Time over threshold and Time of arrival can be acquired
- Preamp polarity can be changed



# Set up of DAQ

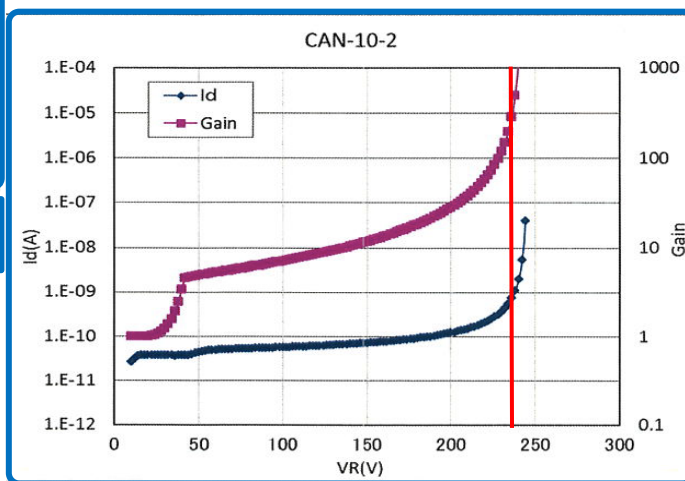
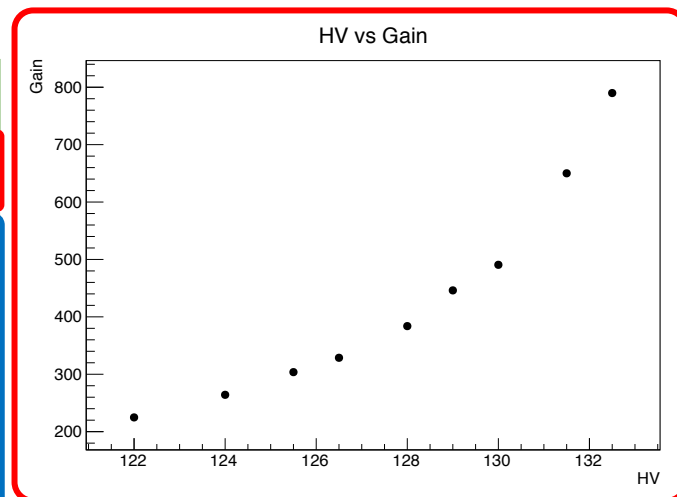
## ➤ Measurement

Model number	Type	HV	Gain at each HV
S12023-10A	Reach-through	129 V	450 (Measured value)
S8664-10K	Inverse	407 V	about 500~1000
pkg-10	Reach-through	240 V	about 1000
pkg-20	Reach-through	110 V	about 1000
S2384	Reach-through	149 V	about 1000
S3884	Reach-through	179 V	about 1000
S8664-20K	Inverse	415 V	about 500~1000
S8664-55	Inverse	415 V	about 500~1000

Hamamatsu datasheets

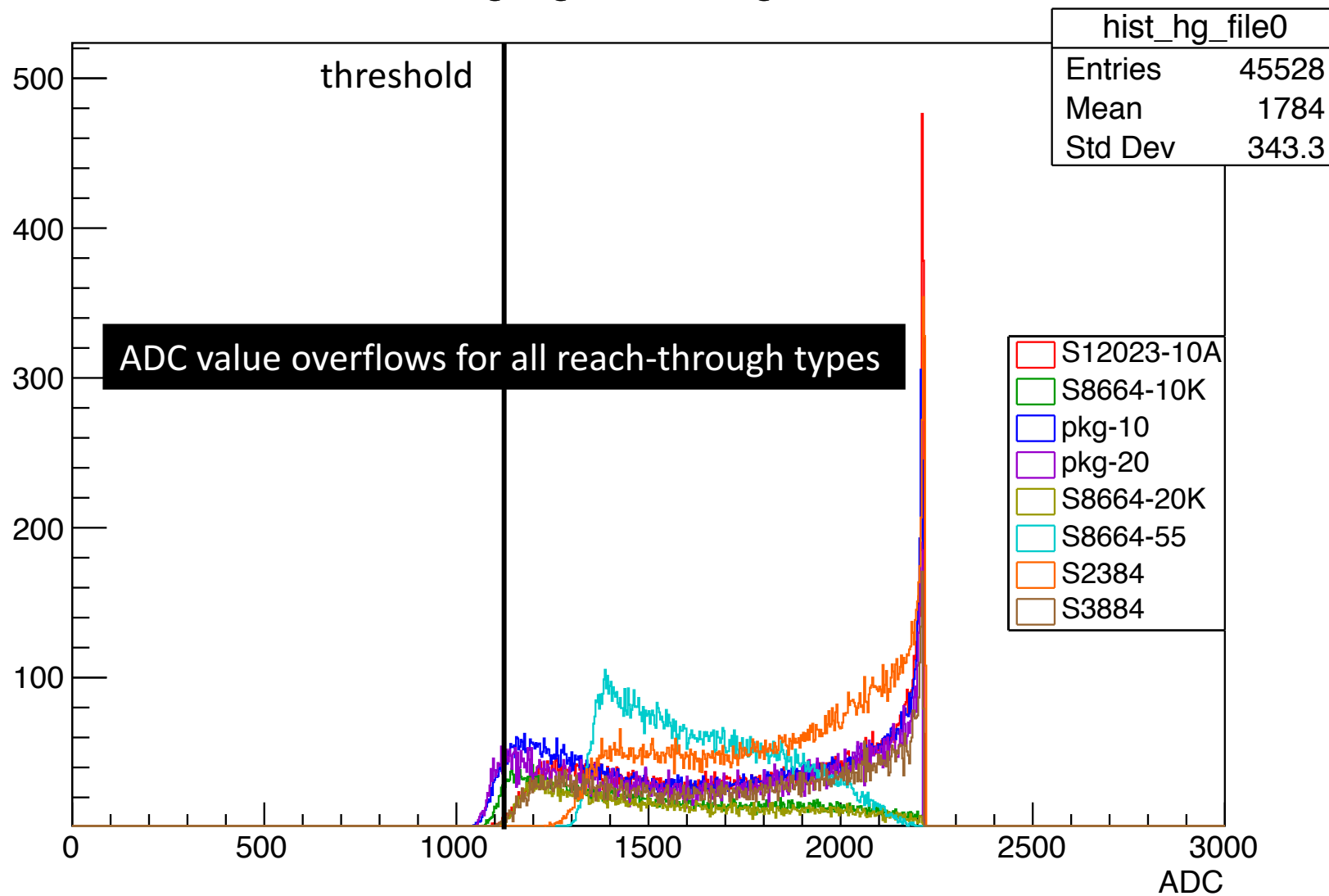
- S12023-10 : The Gain value is measured by DAQ with the  $\gamma$  source

- Other APDs : The Gain value is referenced by datasheet



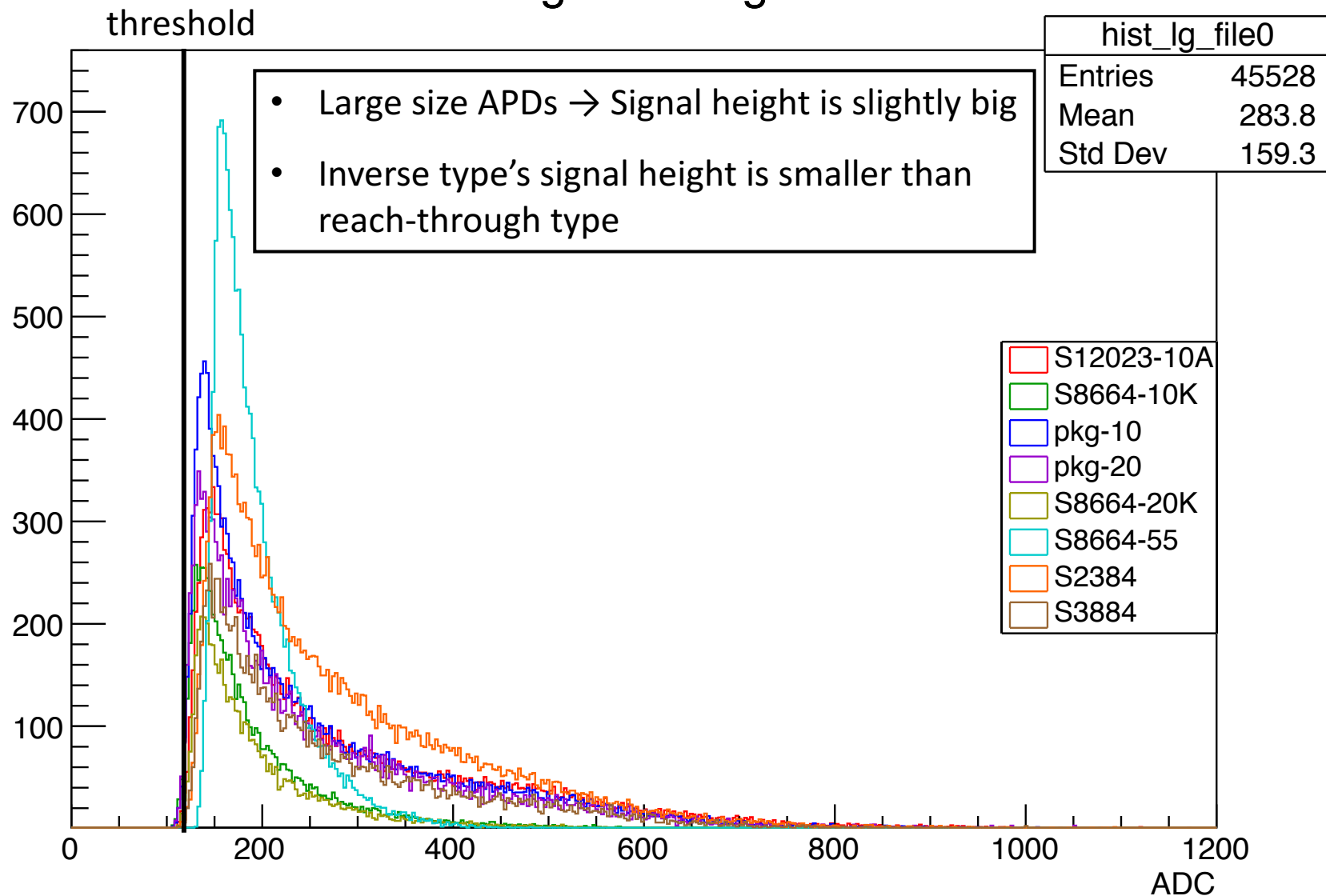
# Result

## High gain histogram



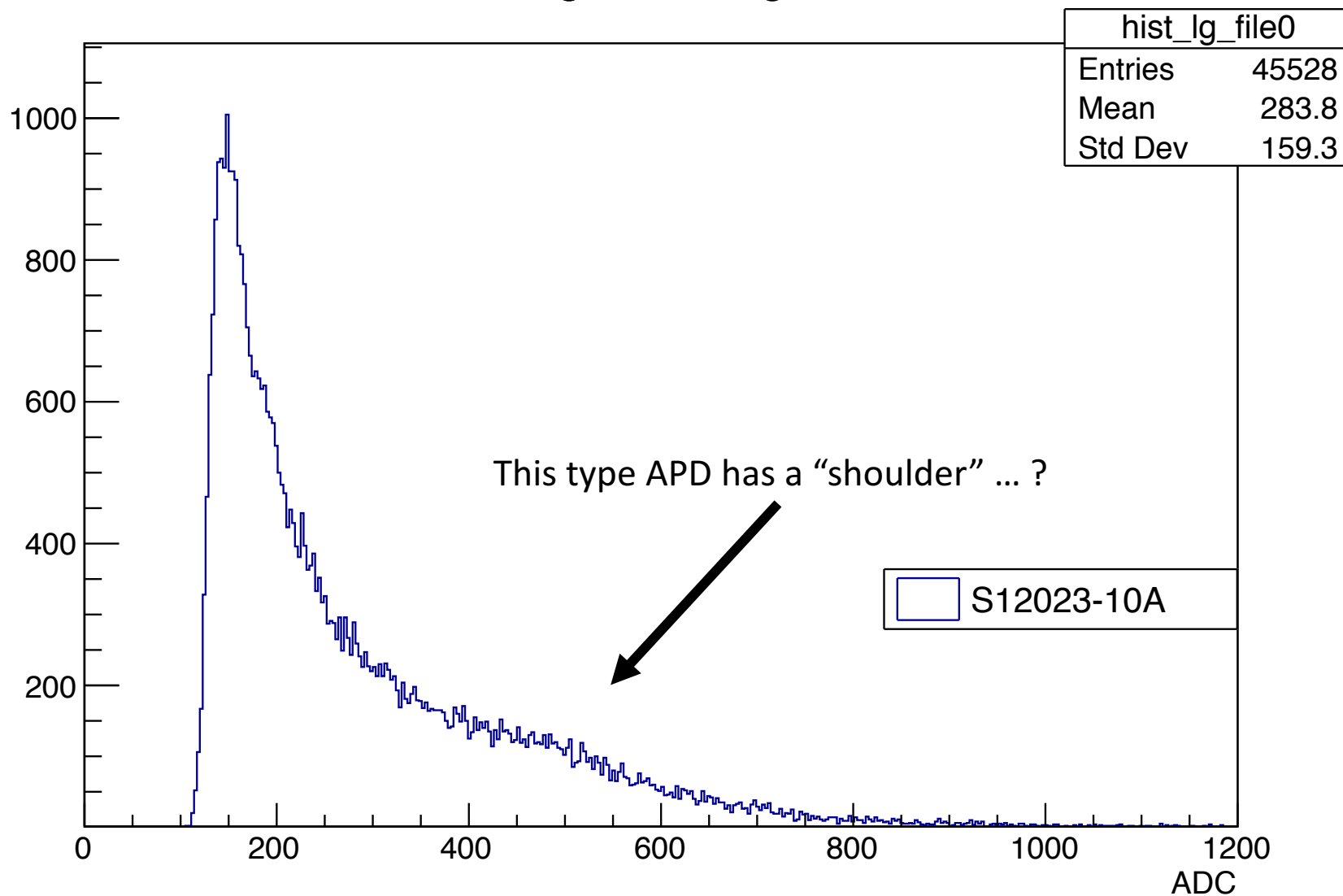
# Result

## Low gain histogram



# Result

## Low gain histogram



# Result

Due to the gain variation inside the APD, signals by  $^{90}\text{Sr}$  will be landau distribution for each gain (such as black lines), and the total distribution can be like red line



The “shoulder” will be made by the landau distribution of the maximum gain

The active thickness can be calculated using the “shoulder”

The relation between ADC output and Charge of SKIROC2cms are known (such as right figure)

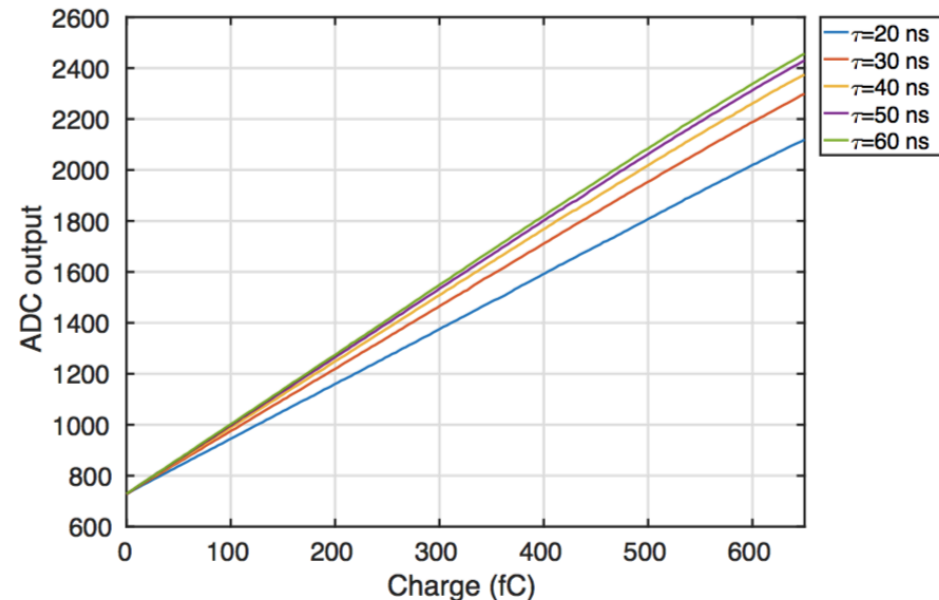
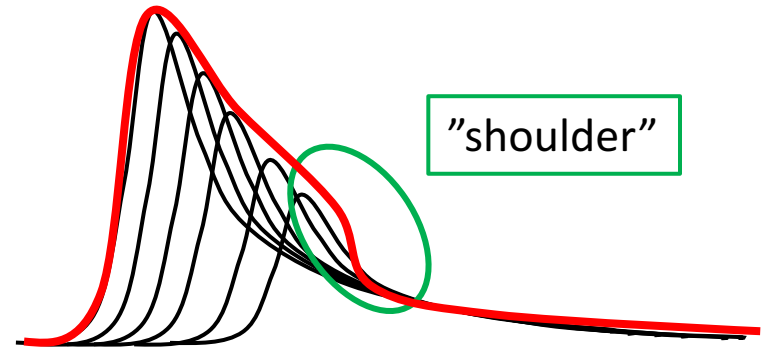


Figure 19: Low-gain transfer function for different shaper settings.



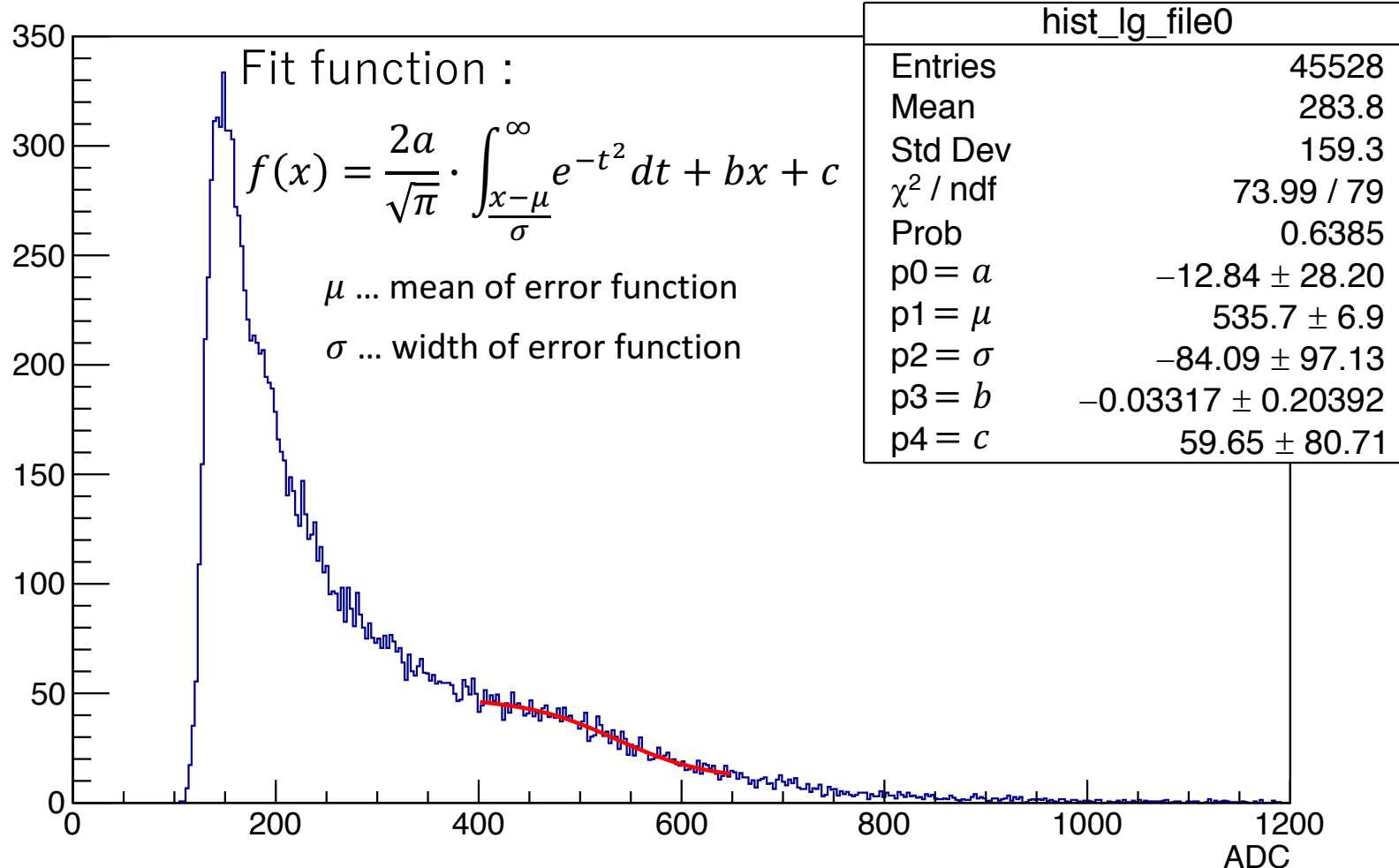
# Result

## ➤ S12023-10A (reach-through)

### Low gain histogram



S12023-10A



# Result

A MIP particle makes 76 electron and hole pairs per 1  $\mu\text{m}$  in a silicon sensor

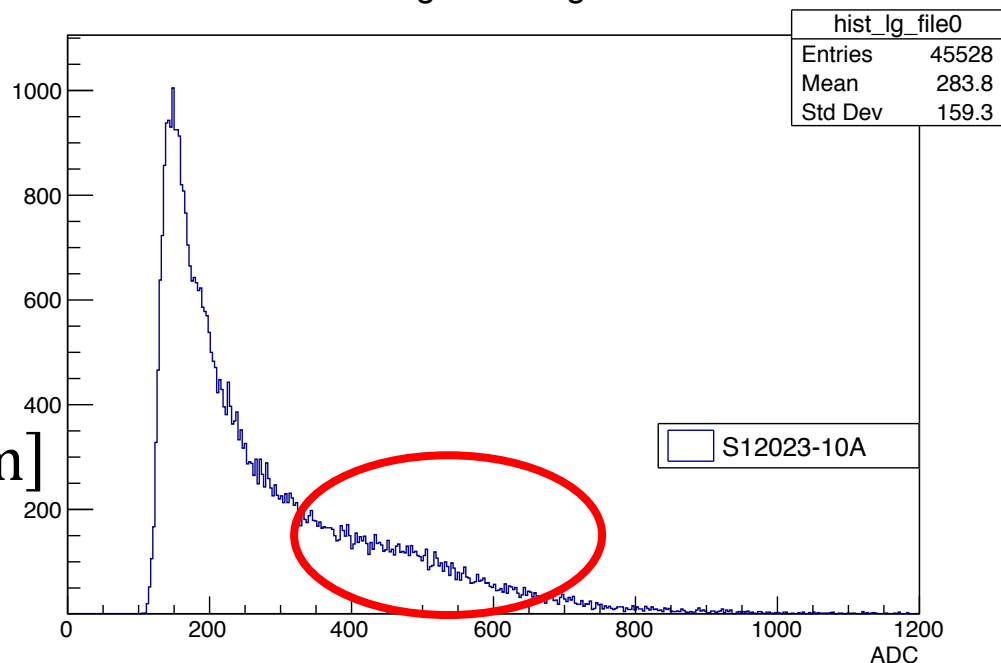


$$\text{Thickness} = \frac{\text{ADC output}}{a} \cdot \frac{1}{\text{Gain}} \cdot \frac{1}{76 \cdot e} \quad [\mu\text{m}]$$

$$a = \text{ADC output} / \text{Charge} [/\text{C}]$$
$$= 2.25 \times 10^{-16}$$

$e$  = Elementary charge [C]

Low gain histogram



Active thickness of S12023-10A :  $\sim 20 \mu\text{m}$

# Preparation of Test Beam

✓ Place : ELPH (Tohoku University)

➤ Basic characteristics

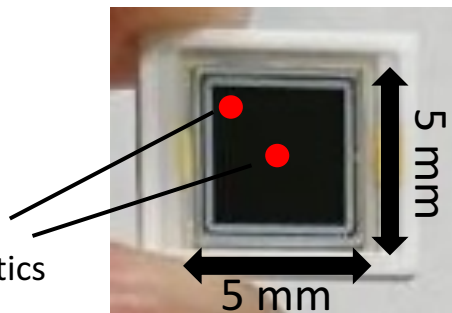
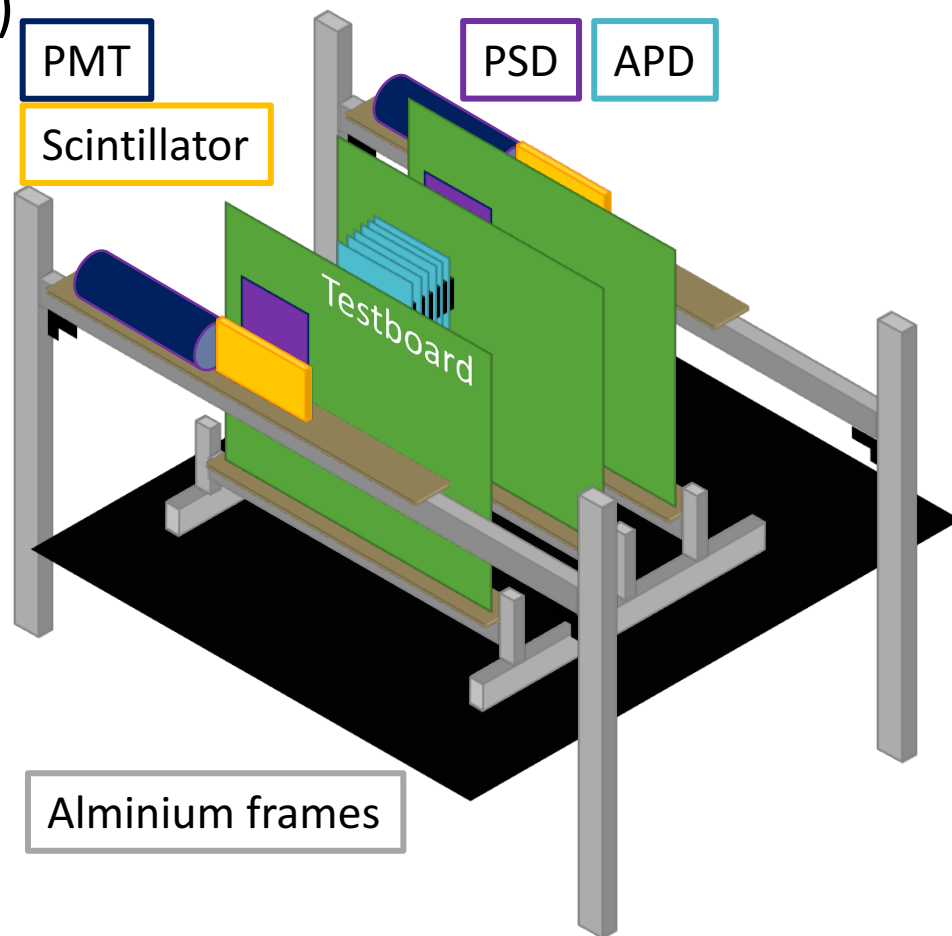
- Active thickness
- Comparison between Reach-through type and Inverse type

➤ Time resolution

- Measurement time resolution using the three identical type APDs

➤ Position dependence in sensor

- ADC measurement at several points in a sensor

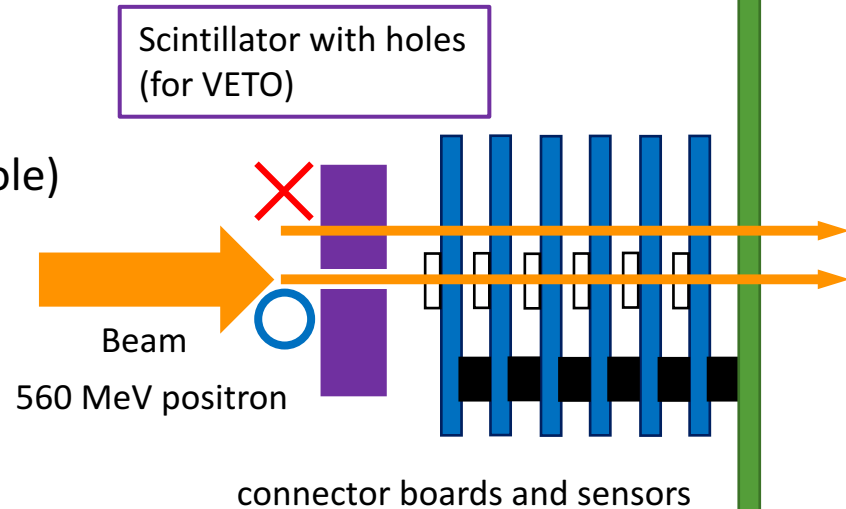
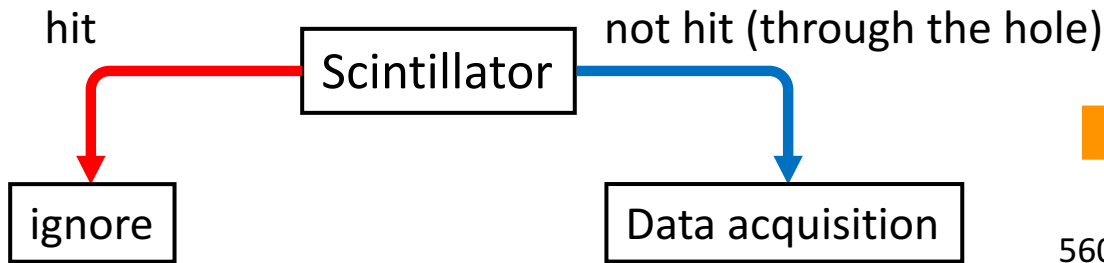


Compare the characteristics at the center and corner

# Preparation of Test Beam

## ➤ Active collimator

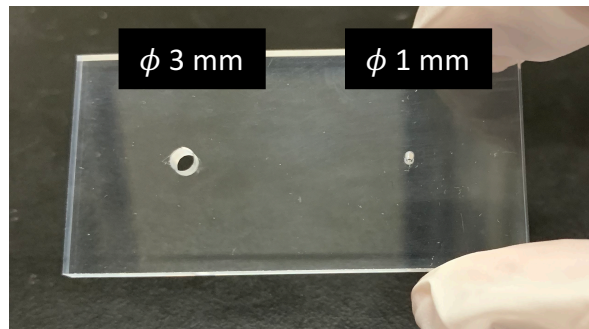
Scintillators will be used as collimator



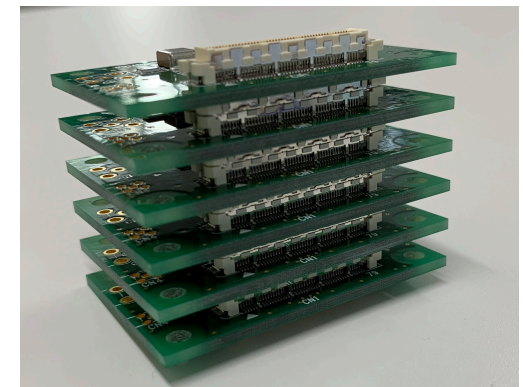
↓ The signal of scintillator is read out by PMT



PMT



Scintillator



stacking connector boards

# Summary

- Signal heights are measured with 8 types of APDs for development of LGADs
- SKIROC2cms was used to take data
- Differences between reach-through type and inverse type were obtained
- In S12023-10A (reach-through), the active thickness was estimated
- Test Beam preparation is ongoing

## ➤ Next plan

- Analysis of the Test Beam data Preparation for Test Beam
- Producing the LGAD prototype for ILC